

GP1S50/GP1S51 /GP1S52

Compact Photointerrupter

Features

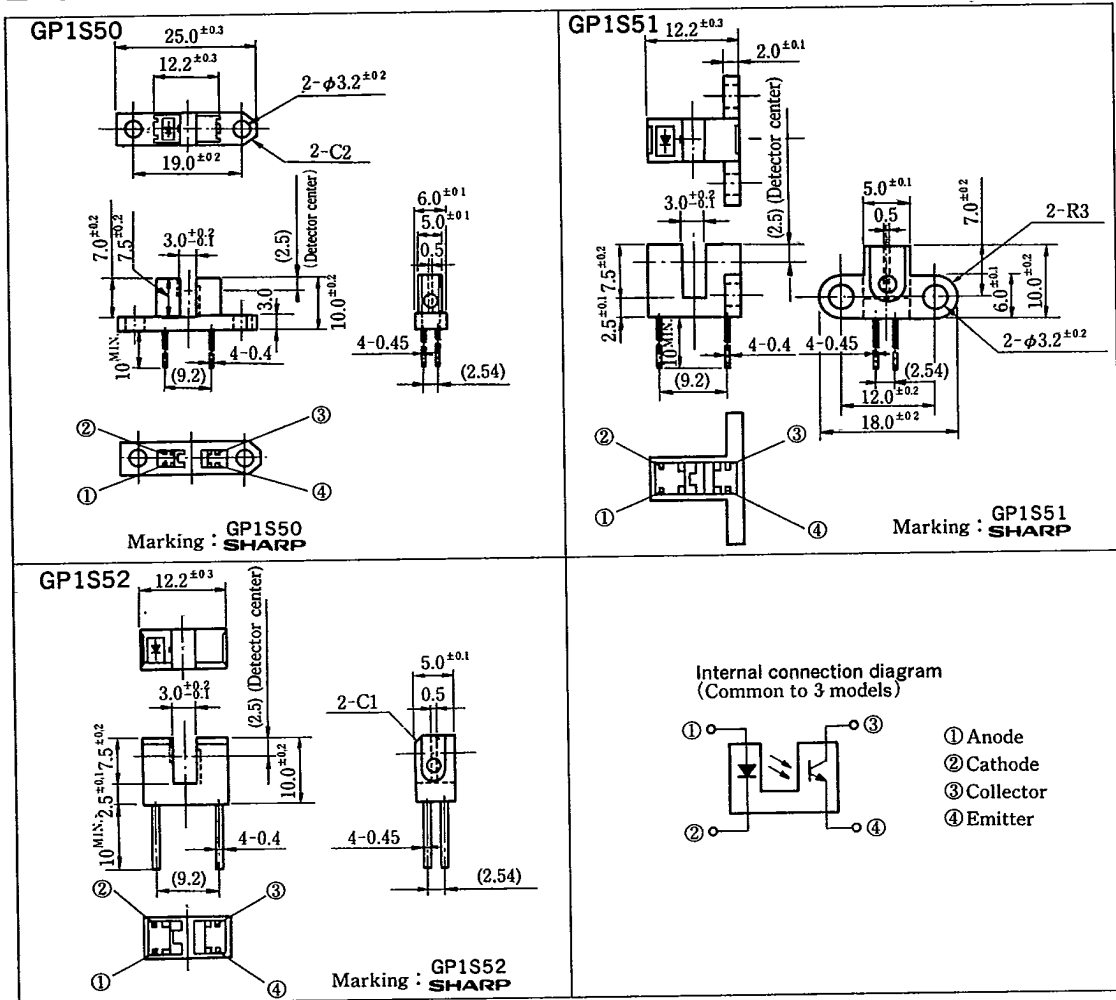
1. Compact type
2. High sensing accuracy (Slit width : 0.5mm)
3. Both-sides mounting type : GP1S50
Either-side mounting type : GP1S51
PWB direct mounting type : GP1S52

Applications

1. OA equipment, such as FDDs, printers, facsimiles
2. VCRs

Outline Dimensions

(Unit : mm)



T-41-73

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50 mA
	*1 Peak forward current	I_{FM}	1 A
	Reverse voltage	V_R	6 V
	Power dissipation	P	75 mW
Output	Collector-emitter voltage	V_{CEO}	35 V
	Emitter-collector voltage	V_{ECO}	6 V
	Collector current	I_C	20 mA
	Collector power dissipation	P_C	75 mW
Operating temperature	T_{OPR}	-25 ~ +85	°C
Storage temperature	T_{STG}	-40 ~ +100	°C
*2 Soldering temperature	T_{SOL}	260	°C

*1 Pulsj width $\leq 100\mu s$, Duty ratio = 0.01

*2 For 5 seconds

Electro-optical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V_F $I_F=20mA$	—	1.25	1.4	V
	Peak forward voltage	V_{FM} $I_{FM}=0.5A$	—	3	4	V
	Reverse current	I_R $V_R=3V$	—	—	10	μA
Output	Collector dark current	I_{CEO} $V_{CE}=20V$	—	10^{-9}	10^{-7}	A
Transfer characteristics	Current transfer ratio	CTR $I_F=20mA, V_{CE}=5V$	2.5	—	25	%
	Collector-emitter saturation voltage	$V_{CE(SAT)}$ $I_F=40mA, I_C=0.5mA$	—	—	0.4	V
	Response time (Rise)	t_R $V_{CE}=2V, I_C=2mA$	—	3	15	μs
	Response time (Fall)	t_F $R_L=100\Omega$	—	4	20	μs

Fig. 1 Forward Current vs. Ambient Temperature

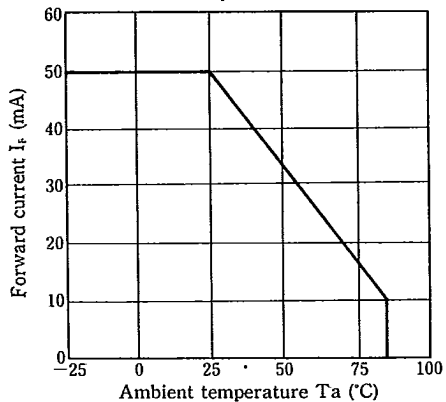


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

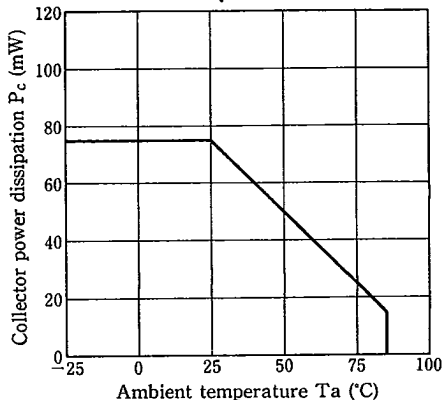


Fig. 3 Peak Forward Current vs. Duty Ratio

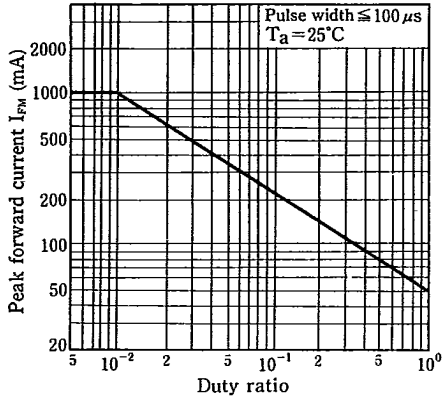


Fig. 4 Forward Current vs. Forward Voltage

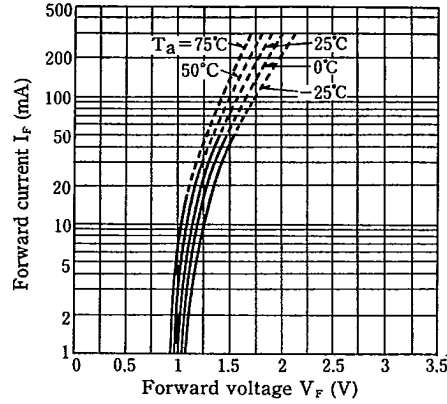


Fig. 5 Collector Current vs. Forward Current

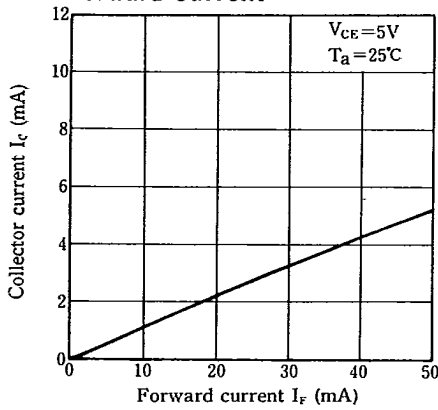


Fig. 6 Collector Current vs. Collector-emitter Voltage

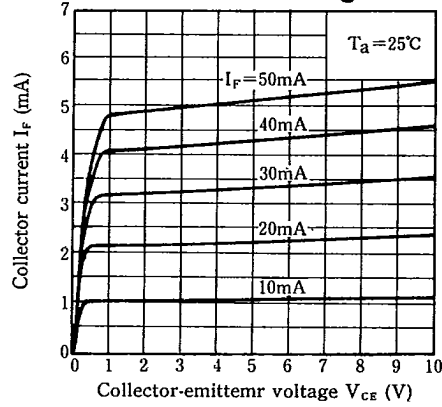


Fig. 7 Collector Current vs. Ambient Temperature

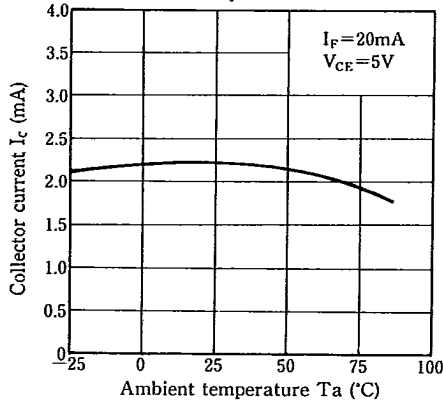
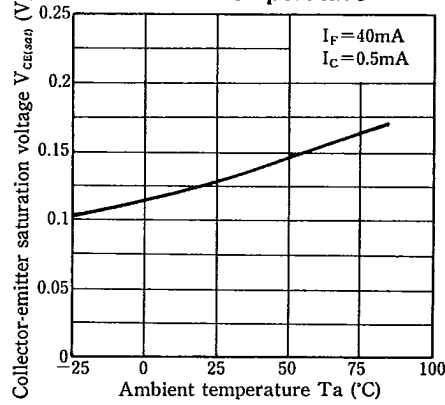
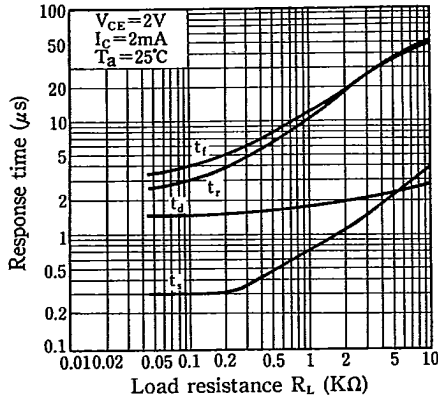


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature



T-41-73

Fig. 9 Response Time vs. Load Resistance



Test Circuit for Response Time

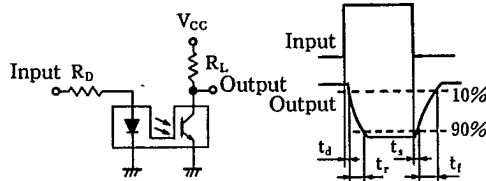


Fig. 10 Frequency Response

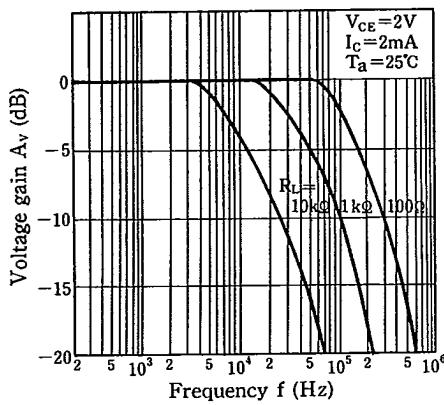


Fig. 11 Collector Dark Current vs. Ambient Temperature

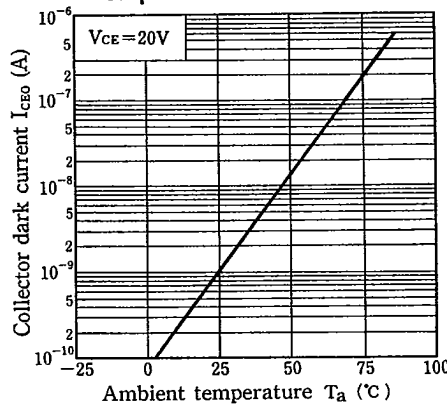


Fig. 12 Relative Collector Current vs. Shield Distance (1)

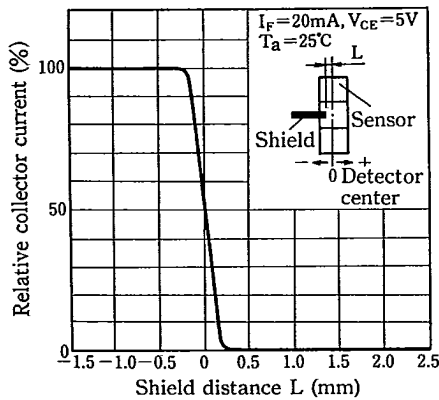


Fig. 13 Relative Collector Current vs. Shield Distance (2)

